

Nobuyoshi Saito

List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	High-Mobility and H ₂ -Anneal Tolerant InGaSiO/InGaZnO/InGaSiO Double Hetero Channel Thin Film Transistor for Si-LSI Compatible Process. IEEE Journal of the Electron Devices Society, 2018, 6, 500-505.	2.1	19
2	Origin of High Mobility in InSnZnO MOSFETs. IEEE Journal of the Electron Devices Society, 2018, 6, 1253-1257.	2.1	10
3	High mobility ($>30 \text{ cm}^2/\text{Vs}$) and low source/drain parasitic resistance In ⁺ Zn ⁺ O BEOL transistor with ultralow $<10^{-14} \text{ A}$ off-state leakage current. Japanese Journal of Applied Physics, 2019, 58, SBBJ07.	1.5	9
4	High thermal stability of doped oxide semiconductor for monolithic 3D integration. MRS Bulletin, 2021, 46, 1044-1052.	3.5	4